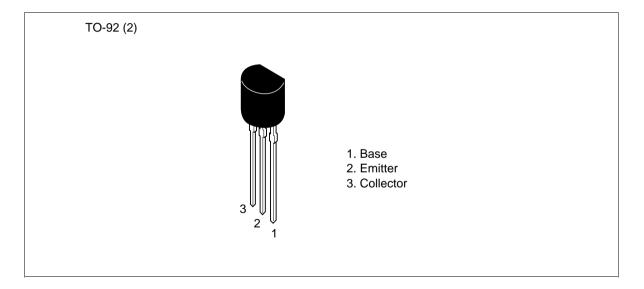
Silicon NPN Epitaxial Planar

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Application

VHF Wide band amplifier

Outline



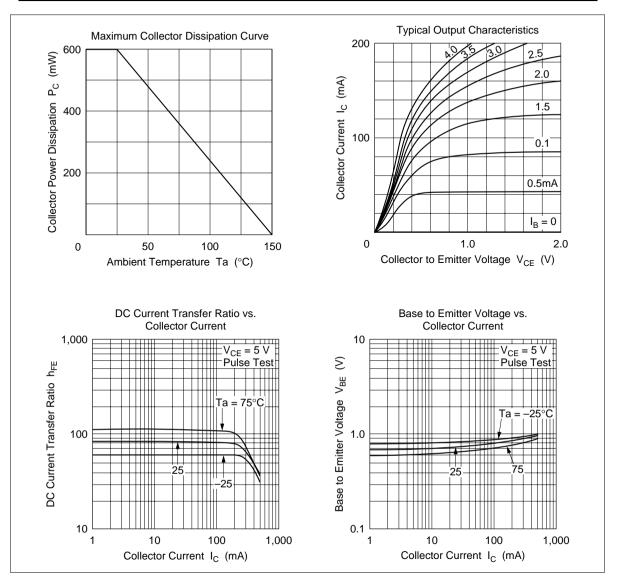


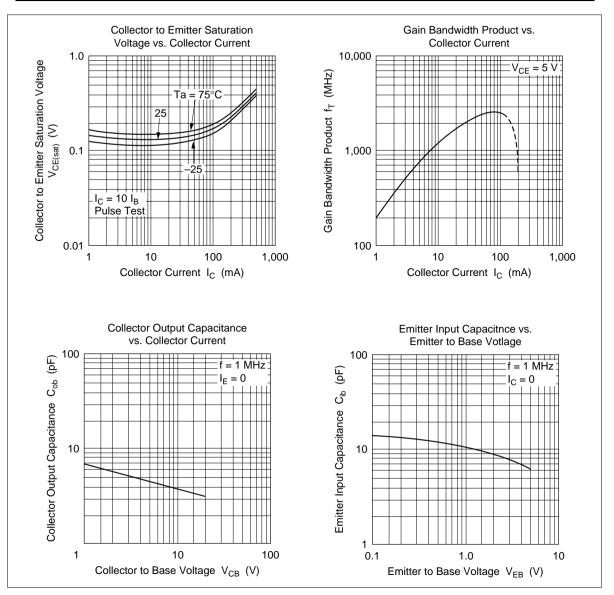
Absolute Maximum Ratings $(Ta = 25^{\circ}C)$

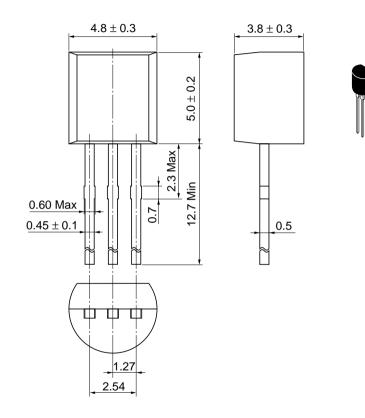
Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	30	V
Collector to emitter voltage	V _{CEO}	20	V
Emitter to base voltage	V _{EBO}	3	V
Collector current	Ι _c	300	mA
Collector peak current	i _{C (peak)}	500	mA
Collector power dissipation	Pc	600	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Мах	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	30	—	—	V	$I_{c} = 100 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	20	_	—	V	$I_c = 1 \text{ mA}, R_{BE} = \infty$
Collector cutoff current	I _{CBO}	_	—	1	μΑ	$V_{CB} = 25 \text{ V}, \text{ I}_{E} = 0$
Emitter cutoff current	I _{EBO}	—	—	10	μΑ	$V_{EB} = 3 V, I_{E} = 0$
DC current transfer ratio	h_{FE}	50	—	200		$V_{ce} = 5 \text{ V}, \text{ I}_{c} = 50 \text{ mA}$
Gain bandwidth product	f _T	1.5	2.5	—	GHz	$V_{ce} = 5 \text{ V}, \text{ I}_{c} = 50 \text{ mA}$
Collector output capacitance	Cob	_	4.0	—	pF	$V_{_{CB}} = 10 \text{ V}, \text{ I}_{_{E}} = 0, \text{ f} = 1 \text{ MHz}$







Hitachi Code	TO-92 (2)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 g

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